Buffer with Open Drain Output

The NL17SG07E MiniGate[™] is an advanced high-speed CMOS Buffer with Open Drain Output in ultra-small footprint.

The NL17SG07E input and output structures provide protection when voltages up to 3.6 V are applied regardless of the supply voltage.

Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: $t_{PD} = 2.5$ ns (Typ) at $V_{CC} = 3.0$ V, $C_L = 15$ pF
- Low Power Dissipation: $I_{CC} = 0.5 \mu A$ (Max) at $T_A = 25^{\circ}C$
- 3.6 V Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

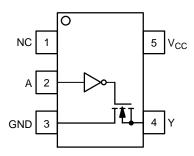


Figure 1. SC-88A (Top View)



Figure 2. Logic Symbol



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SC-88A DF SUFFIX CASE 419A



MARKING

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT

PIN	NAME
1	NC
2	А
3	GND
4	Y
5	V _{CC}

FUNCTION TABLE

Input A	Output Y
L	L
Н	Z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	-0.5 to +4.6	V
V _{IN}	DC Input Voltage	-0.5 to +4.6	V
V _{OUT}	DC Output Voltage Active Mode, LOW State Tri–State Mode, Output at Hi–Z State Power–Down Mode (V_{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +4.6 -0.5 to +4.6	V
I _{IK}	DC Input Diode Current V _{IN} < GND	-20	mA
I _{OK}	DC Output Diode Current V _{OUT} < GND	-20	mA
I _{OUT}	DC Output Source/Sink Current	±20	mA
I _{CC}	DC Supply Current per Supply Pin	±20	mA
I _{GND}	DC Ground Current per Ground Pin	±20	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias	+150	°C
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 2)	>2000	V
I _{LATCHUP}	Latch-up Performance above V _{CC} and below GND at 125°C (Note 3)	±75	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
 Tested to EIA/JESD22-A114-A.
- 3. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Char	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage		0.9	3.6	V
V_{IN}	Digital Input Voltage		0.0	3.6	V
V _{OUT}	Output Voltage	Output at Low State Tri–State Mode, Output at Hi–Z State Power–Down Mode ($V_{\rm CC}$ = 0 V)	0.0 0.0 0.0	V _{CC} 3.6 3.6	V
T _A	Operating Temperature Range		-55	+125	°C
Δt / ΔV	Input Transition Rise or Fail Rate	V_{CC} = 3.3 V \pm 0.3 V	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

				V _{CC}		T _A = 25°C	;	-55°C ≤ 1	Γ _A ≤ 125°C	
Symbol	Parameter	С	ondition	(V)	Min	Тур	Max	Min	Max	Unit
V_{IH}	/ _{IH} High-Level			0.9	V _{CC}			V _{CC}		
	Input Voltage			1.1 to 1.3	0.70 x V _{CC}			0.70 x V _{CC}		
				1.4 to 1.6	0.65 x V _{CC}			0.65 x V _{CC}		V
				1.65 to 1.95	0.65 x V _{CC}			0.65 x V _{CC}		
				2.3 to 2.7	1.7			1.7		
				3.0 to 3.6	2.0			2.0		
V _{IL}	Low-Level			0.9			GND		GND	
	Input Voltage			1.1 to 1.3			0.30 x V _{CC}		0.30 x V _{CC}	
				1.4 to 1.6			0.35 x V _{CC}		0.35 x V _{CC}	V
				1.65 to 1.95			0.35 x V _{CC}		0.35 x V _{CC}	
				2.3 to 2.7			0.7		0.7	1
				3.0 to 3.6			0.8		0.8	
V _{OL}	Low-Level	V _{IN} =	I _{OL} = 20 μA	0.9			0.1		0.1	V
	Output Voltage	V _{IH} or V _{IL}	I _{OL} = 0.3 mA	1.1 to 1.3			0.25 x V _{CC}		0.25 x V _{CC}	
			I _{OL} = 1.7 mA	1.4 to 1.6			0.25 x V _{CC}		0.25 x V _{CC}	
			I _{OL} = 3.0 mA	1.65 to 1.95			0.45		0.45	
			I _{OL} = 4.0 mA	2.3 to 2.7			0.4		0.4	-
			$I_{OL} = 8.0 \text{ mA}$	3.0 to 3.6			0.4		0.4	
I _{IN}	Input Leakage Current	V _{IN}	= 0 to 3.6 V	0.9 to 3.6			±0.1		±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND		3.6			0.5		10	μΑ
l _{OZ}	Output Tri– State Leakage Current	$V_{IN} = V_{IH}$ or V_{IL} , $V_{OUT} = 0$ to 3.6 V		0.9 to 3.6			1.0		10	μΑ
l _{OFF}	Power Off Leakage Cur- rent	V _{IN} V _{OUT}	= 0 to 3.6 V = 0 to 3.6 V	0			1.0		10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

					T _A = 25°C	;	T _A = -55°C to +125°C		
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Uni
t _{PZL} Propagation Delay,	$C_L = 10 \text{ pF},$	0.9	-	12	_	-	-	ns	
	Enable Time,	$R_1 = R_L = 5 \text{ k}\Omega$	1.1 to 1.3	-	5.5	7.9	-	9.0	1
	A to Y		1.4 to 1.6	-	4.0	5.7	-	7.3	1
			1.65 to 1.95	_	3.3	3.9	_	5.9	1
			2.3 to 2.7	_	2.7	3.3	_	4.5	1
			3.0 to 3.6	-	2.4	2.9	-	3.7	
		$C_L = 15 pF$,	0.9	-	12.5	_	-	-	n
		$R_1 = R_L = 5 \text{ k}\Omega$	1.1 to 1.3	-	5.8	8.1	-	9.2	
			1.4 to 1.6	-	4.1	6.0	-	7.4	
			1.65 to 1.95	_	3.4	4.0	_	6.2	
			2.3 to 2.7	_	2.8	3.4	_	4.6	
			3.0 to 3.6	-	2.5	3.0	_	3.7	
		C _L = 30 pF,	0.9	_	13.2	_	_	_	n
		$R_1 = R_L = 5 \text{ k}\Omega$	1.1 to 1.3	-	6.2	8.7	_	9.8	
			1.4 to 1.6	-	4.5	6.2	_	7.6	
		1.65 to 1.95	-	3.5	4.2	_	6.4		
		2.3 to 2.7	-	3.0	3.6	_	4.7		
		3.0 to 3.6	-	2.6	3.1	_	3.9		
t _{PLZ}	Propagation Delay,	$C_L = 10 \text{ pF},$	0.9	_	8.0	-	_	-	n
	Disable Time,	$R_1 = R_L = 5 \text{ k}\Omega$	1.1 to 1.3	-	6.5	10.9	-	11.5	ns
	A to Y		1.4 to 1.6	-	5.2	8.9	-	9.5	
			1.65 to 1.95	-	4.9	8.8	-	9.4	
			2.3 to 2.7	-	3.8	8.4	-	9.3	
			3.0 to 3.6	-	3.5	8.1	-	8.5	
		C _L = 15 pF,	0.9	-	11.1	_	-	-	
		$R_1 = R_L = 5 \text{ k}\Omega$	1.1 to 1.3	-	9.0	13.4	-	14	
			1.4 to 1.6	-	7.9	11.4	-	12.0	
			1.65 to 1.95	-	7.6	11.3	-	11.9	
			2.3 to 2.7	-	6.3	10.9	-	11.8	
			3.0 to 3.6	-	6.0	10.6	-	11.0	
		$C_L = 30 \text{ pF},$ $R_1 = R_L = 5 \text{ k}\Omega$	0.9	-	16.2	-	-	-	n
		$R_1 = R_L = 5 \text{ k}\Omega$	1.1 to 1.3	-	14	20.2	-	20	1
			1.4 to 1.6	-	13	18.9	-	19.5	1
			1.65 to 1.95	-	12.5	18.8	-	19.4	1
		2.3 to 2.7	_	11.2	18.4	-	19.3	1	
		3.0 to 3.6	_	11	18.1	-	18.3	1	
C _{IN}	Input Capacitance		0 to 3.6	_	3	_	_	_	pl
C _{PD}	Power Dissipation Capacitance (Note 4)		0.9 to 3.6	-	4	_	_	_	pl

^{4.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

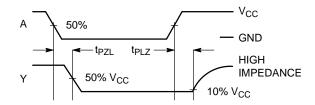


Figure 3. Switching Waveform

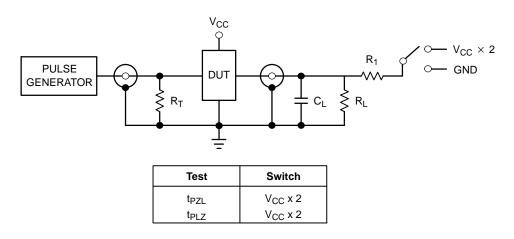


Figure 4. Test Circuit

ORDERING INFORMATION

Device	Package	Shipping [†]
NL17SG07EDFT2G	SC-88A (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

DATE 17 JAN 2013



- TIES:
 DIMENSIONING AND TOLERANCING
 PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
 DIMENSIONS A AND B DO NOT INCLUDE
- MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

-B-S D 5 PL 0.2 (0.008) M B M **SOLDER FOOTPRINT**

+++			
0.40			0.65 0.025
	<u>1.9</u> 0.0748	SCALE 20:1	$\left(\frac{\text{mm}}{\text{inches}}\right)$
OT # F 4	07450	07.45.0	

0.50 0.0197

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	2. EMITTER	2. N/C	2. DRAIN 1/2	2. COMMON ANODE
3. BASE	3. BASE	3. ANODE 2	3. SOURCE 1	3. CATHODE 2
4. COLLECTOR	4. COLLECTOR	4. CATHODE 2	4. GATE 1	4. CATHODE 3
4. COLLECTOR	4. COLLECTOR	4. CATHODE 2	4. GATE 1	4. CATHODE 3
5. COLLECTOR	5. CATHODE	5. CATHODE 1	5. GATE 2	5. CATHODE 4

J. GOLLLOTON	3. CATTODE	J. CATHODE I	J. GAIL 2	J. CATTODE 4
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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74AUP1G34FW5-7 74AUP1G07FW5-7 74LVC2G126RA3-7 NLX2G17CMUTCG 74LVCE1G125FZ4-7 Le87501NQC 74AUP1G126FW5-7 TC74HC4050AP(F) 74LVCE1G07FZ4-7 NLX3G16DMUTCG NLX2G06AMUTCG NLVVHC1G50DFT2G NLU2G17AMUTCG
LE87100NQC LE87290YQC LE87290YQCT LE87511NQC LE87511NQCT LE87557NQC LE87557NQCT LE87614MQC
LE87614MQCT 74AUP1G125FW5-7 NLU2G16CMUTCG MC74LCX244MN2TWG NLV74VHC125DTR2G NL17SG126DFT2G